	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Errors
1	IS&R	L1	2	("20030089899").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/03/16 15:12			
2	IS&R	L2	2	("20040145053").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/03/16 15:13			
3	IS&R	L3	2	("6670693").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/03/16 15:13			
4	BRS	L4	46	nano$ with wide with (bandgap or band near gap) with semiconductor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/03/16 15:16			
5	BRS	L5	38	nano$ with wide with (bandgap or band near gap) with semiconductor and (heat$5 or thermal)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/03/16 15:18			

	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Errors
6	BRS	L6	31	nano$ with wide with (bandgap or band near gap) with semiconductor and (heat$5 or thermal) and (irradiat$5 or radiat$5 or beam or laser)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/03/16 15:20			

	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Errors
1	IS&R	L1	2	("20030089899").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/03/16 15:12			
2	IS&R	L2	2	("20040145053").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/03/16 15:13			
3	IS&R	L3	2	("6670693").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/03/16 15:13			
4	BRS	L4	46	nano$ with wide with (bandgap or band near gap) with semiconductor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/03/16 15:16			
5	BRS	L5	38	nano$ with wide with (bandgap or band near gap) with semiconductor and (heat$5 or thermal)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/03/16 17:38			

	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Errors
6	BRS	L6	31	nano$ with wide with (bandgap or band near gap) with semiconductor and (heat$5 or thermal) and (irradiat$5 or radiat$5 or beam or laser)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/03/16 15:20			

	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Errors
7	BRS	L7	31	("20010054305" | "20020008191" | "20030052701" | "4189516" | "4265124" | "4511816" | "4937454" | "5109844" | "5155364" | "5229569" | "5343107" | "5354980" | "5385862" | "5456797" | "5464984" | "5510481" | "5677538" | "5935155" | "5936247" | "5944747" | "5992215" | "6084503" | "6137231" | "6144332" | "6243517" | "6282357" | "6312568" | "6450008" | "6501107" | "6518637" | "6567753").PN. OR ("6853075").URPN.	US-PGPUB; USPAT; USOCR	2005/03/16 17:37			

	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Errors
8	BRS	L9	2	nano$ and wide with (bandgap or band near gap) with semiconductor with (heat$5 or thermal) with (source or drain or gate)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/03/16 17:39			
9	BRS	L8	28	nano$ and wide with (bandgap or band near gap) with semiconductor with (heat$5 or thermal)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/03/16 17:44			
10	BRS	L10	146	wide with (bandgap or band near gap) with semiconductor with (heat$5 or thermal or irradiat$5 with (laser or beam))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/03/16 17:46			

	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Errors
11	BRS	L11	7	wide with (bandgap or band near gap) with semiconductor with (heat$5 or thermal or irradiat$5 with (laser or beam)) with (source or drain or gate)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/03/16 18:02			
12	IS&R	L12	2	("6271576").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/03/16 18:00			
13	BRS	L13	0	wide with (bandgap or band near gap) with semiconductor with irradiat$5 with laser with (source or drain or gate)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/03/16 18:03			

	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Errors
14	BRS	L14	7	wide with (bandgap or band near gap) with semiconductor with irradiat$5 with laser	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2005/03/16 18:03			
15	BRS	L15	1	2003-224203.NRAN.	DERWENT	2005/03/16 18:07			